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Diodes Incorporated ZXMP6A17E6TA

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# **ZXMP6A17E6**

**60V P-CHANNEL ENHANCEMENT MODE MOSFET** 

# **Product Summary**

V(BR)DSS	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C (Note 6)
-60V	125mΩ @ $V_{GS}$ = -10V	-3.0 A
-00V	190mΩ @ $V_{GS}$ = -4.5V	-2.4 A

# Description

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- **DC-DC Converters**
- **Power Management Functions**
- **Disconnect Switches**
- Motor Control



SOT-26

Top View

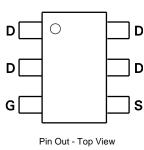
### **Features and Benefits**

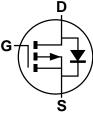
- Low On-Resistance
- Fast Switching Speed
- Low Threshold •
- Low Gate Drive
- Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Mechanical Data**

- Case: SOT-26
- Case Material: Molded Plastic; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208
- Weight: 0.018 grams (Approximate)







Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Compliance	Case	Quantity per reel
ZXMP6A17E6TA	Standard	SOT-26	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Note:

	SOT-2	26
		Π
	6A17	Σ
0		

6A17 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

	Date Code K	ey											
Γ	Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
	Code	С	D	E	F	G	Н		J	K	L	М	Ν

Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D
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Document Number: DS33589 Rev. 5 - 2

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### **ZXMP6A17E6**

#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

(	Characteristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-60	V
Gate-Source Voltage			V <sub>GS</sub>	±20	V
		(Note 6)		-3	
Continuous Drain Current	$V_{GS} = -10V$	$T_{A} = +70^{\circ}C$ (Note 6)	ID	-2.4	А
		(Note 5)		-2.3	
Pulsed Drain Current	V <sub>GS</sub> = -10V	(Note 7)	I <sub>DM</sub>	-13.6	A
Continuous Source Current (Body Diode)		(Note 6)	I <sub>S</sub>	-2.5	A
Pulsed Source Current (Body Diode)		(Note 7)	I <sub>SM</sub>	-13.6	Α

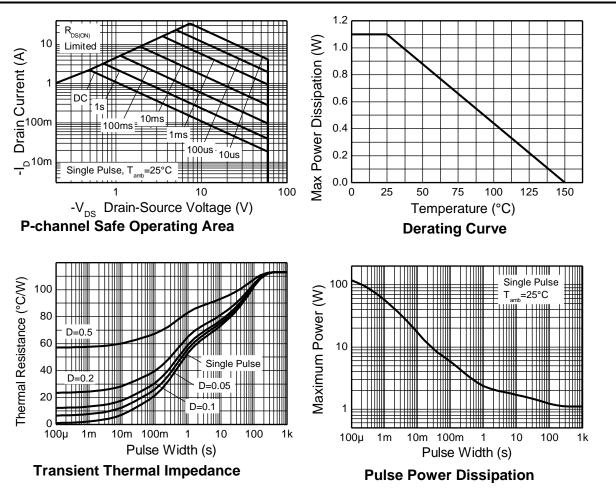
#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.92 15.4	mW/°C
Thermal Resistance, Junction to Ambient	(Note 5)	Paul	113	°C/W
Thermal Resistance, Junction to Amblent	(Note 6)	Reja	65	0/11
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

Notes: 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Same as Note 5, except the device is measured at  $t \le 5$  sec. 7. Same as Note 5, except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.

### **Thermal Characteristics**





Notes:



# ZXMP6A17E6

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test	Condition
OFF CHARACTERISTICS	Cymber		. 76	Шах	Unit	1001	oonanion
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-60			V	I <sub>D</sub> = -250µA, V	35 = 0V
Zero Gate Voltage Drain Current	IDSS	_		-1	μA	$V_{DS} = -60V, V_{C}$	
Gate-Source Leakage	I <sub>GSS</sub>	_		±100	nA	$V_{GS} = \pm 20V, V$	DS = 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1	_	-3	V	I <sub>D</sub> = -250µA, V	<sub>DS</sub> = V <sub>GS</sub>
Static Drain-Source On-Resistance (Note 8)			0.100	0.125	Ω	$V_{GS}$ = -10V, $I_D$	= -2.3A
Static Dialit-Source Off-Resistance (Note 6)	R <sub>DS</sub> (ON)	_	0.130	0.190	12	$V_{GS} = -4.5V, I_{D}$	e = -1.9A
Forward Transconductance (Notes 8 & 9)	<b>g</b> fs	_	4.7	_	S	$V_{DS} = -15V, I_{D}$	= -2.3A
Diode Forward Voltage (Note 8)	V <sub>SD</sub>	_	-0.85	-0.95	V	Is = -2A, V <sub>GS</sub> =	0V
Reverse Recovery Time (Note 9)	t <sub>rr</sub>		25.1		ns	I <sub>F</sub> = -1.7A, di/dt = 100A/µs	
Reverse Recovery Charge (Note 9)	Q <sub>rr</sub>	_	27.2	_	nC	$I_F = -1.7A, dI/d$	$t = 100 \text{A}/\text{\mu}\text{s}$
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	637		pF	$V_{DS} = -30V, V_{GS} = 0V$	
Output Capacitance	Coss	—	70		pF	$v_{DS} = -30v, v_{C}$ - f = 1MHz	SS = 0V
Reverse Transfer Capacitance	C <sub>rss</sub>	_	53		pF		
Total Gate Charge (Note 10)	Qg	_	9.8		nC	$V_{GS} = -5V$	
Total Gate Charge (Note 10)	Qg	_	17.7		nC		$V_{DS} = -30V$
Gate-Source Charge (Note 10)	Q <sub>gs</sub>	_	1.6	_	nC	$V_{GS} = -10V$ $I_D = -2.3A$	
Gate-Drain Charge (Note 10)	Q <sub>gd</sub>	_	4.4		nC		
Turn-On Delay Time (Note 10)	t <sub>D(on)</sub>		2.6		ns	· · · · · · · · · · · · · · · · · · ·	
Turn-On Rise Time (Note 10)	tr	_	3.4		ns	$V_{DD} = -30V, V_{C}$	<sub>65</sub> = -10V
Turn-Off Delay Time (Note 10)	t <sub>D(off)</sub>	_	26.2		ns	$I_D = -1A, R_G \cong$	6Ω
Turn-Off Fall Time (Note 10)	t <sub>f</sub>	_	11.3		ns		

8. Measured under pulsed conditions. Pulse width  $\leq$  300µs; duty cycle  $\leq$  2%.

For design aid only, not subject to production testing.
Switching characteristics are independent of operating junction temperatures.

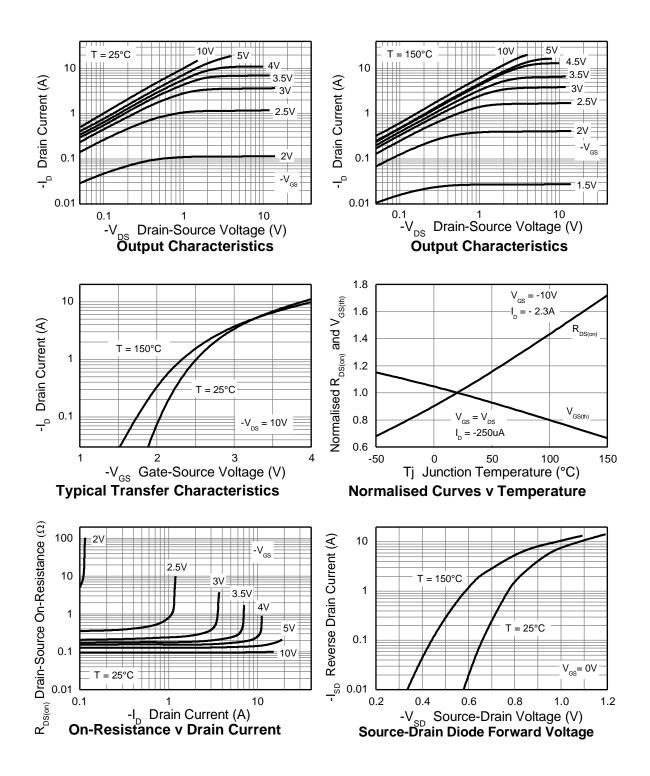
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# **Typical Characteristics**

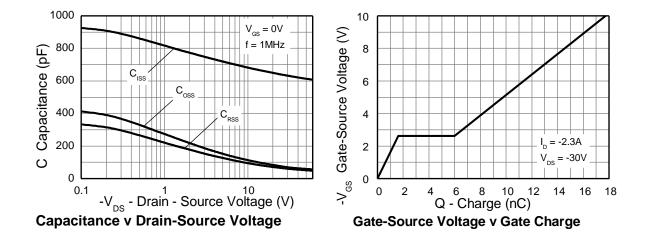




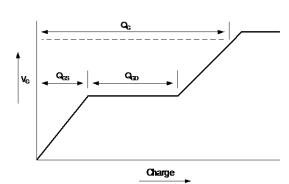


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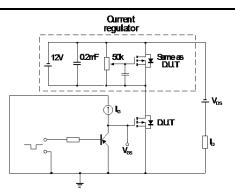
# Typical Characteristics (cont.)



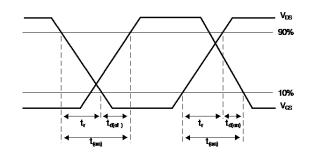
# **Test Circuits**



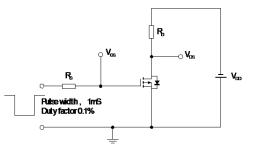
Basic gate charge waveform



Gate charge test circuit









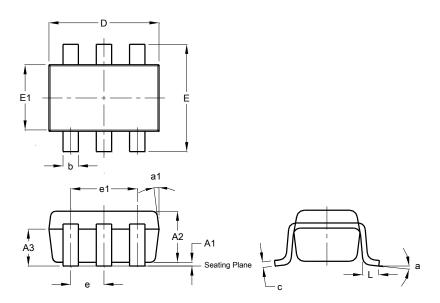




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# **Package Outline Dimensions**

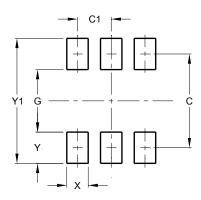
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SC	DT26	
Dim	Min	Max	Тур
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
С	0.10	0.20	0.15
D	2.90	3.10	3.00
е	-	-	0.95
e1	-	-	1.90
Е	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
а	-	-	8°
a1	-	-	7°
All	Dimen	sions i	in mm

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20





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